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Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET

DESCRIPTION

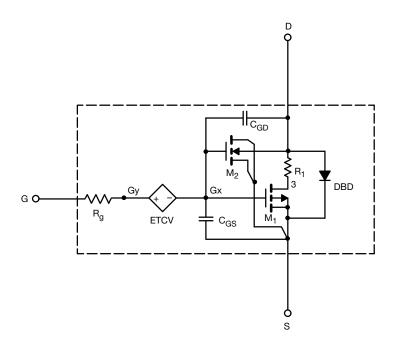
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- Apply for both linear and switching application
- Accurate over the -55 °C to 125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits



SPICE Device Model SQM40081EL

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	2	-	V
Drain-source on-state resistance ^a	D	$V_{GS} = -10 \text{ V}, I_D = -25 \text{ A}$	0.0070	0.0070	Ω
	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -20 A	0.0087	0.0086	
Forward transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, I_D = -25 \text{ A}$	91	92	S
Diode forward voltage	V _{SD}	I _S = -50 A	-0.90	-0.96	V
Dynamic ^b					
Input capacitance	C _{iss}	V _{DS} = -25 V, V _{GS} = 0 V, f = 1 MHz	8600	7365	pF
Output capacitance	C _{oss}		587	576	
Reverse transfer capacitance	C _{rss}		583	548	
Total gate charge	Qg	V _{DS} = -25 V, V _{GS} = -10 V, I _D = -50 A	144	153	nC
Gate-source charge	Q _{gs}		21	34	
Gate-drain charge	Q _{qd}		41	29	

Notes

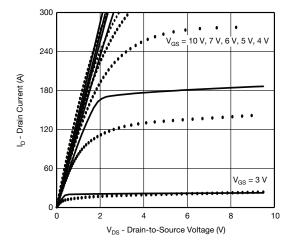
- a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

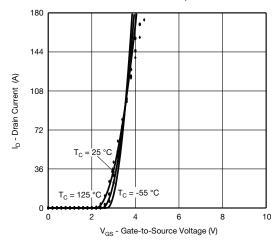


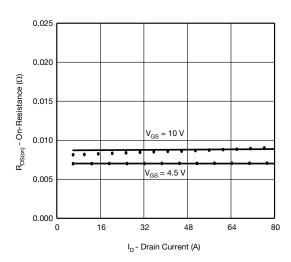
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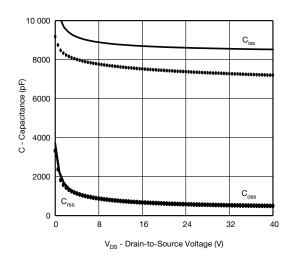
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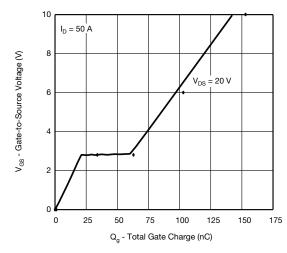
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25~^{\circ}C$, unless otherwise noted)

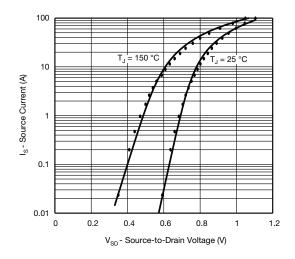












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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